



A Product Line of Diodes Incorporated



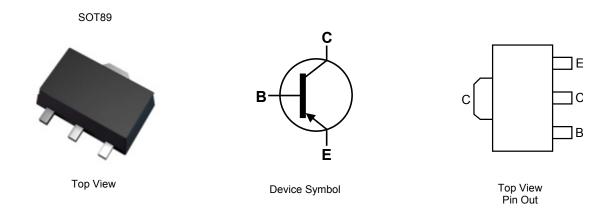
#### **100V PNP MEDIUM POWER TRANSISTOR IN SOT89**

#### Features

- BV<sub>CEO</sub> > -100V
- I<sub>C</sub> = -1A high Continuous Collector Current
- I<sub>CM</sub> = -2A Peak Collector Current
- Low saturation voltage V<sub>CE(sat)</sub> < -200mV @ -250mA</li>
- Complementary NPN type: FCX493
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208<sup>(3)</sup>
- Weight: 0.05 grams (Approximate)



# Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX593TA	P93	7	12	1,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

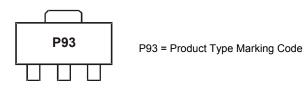
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

Notes:







#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-100	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ι <sub>C</sub>	-1	А
Peak Pulse Current	I <sub>CM</sub>	-2	А

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	PD	1.5	W	
	(Note 7)		2.0		
	(Note 5)		125		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R <sub>0JA</sub>	83		
	(Note 7)		60	°C/W	
Thermal Resistance, Junction to Lead	(Note 8)	R <sub>θJL</sub>	22		
Thermal Resistance, Junction to Case	(Note 9)	R <sub>0JC</sub>	16		
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.

Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.
Thermal resistance from junction to solder-point (on the exposed collector pad).

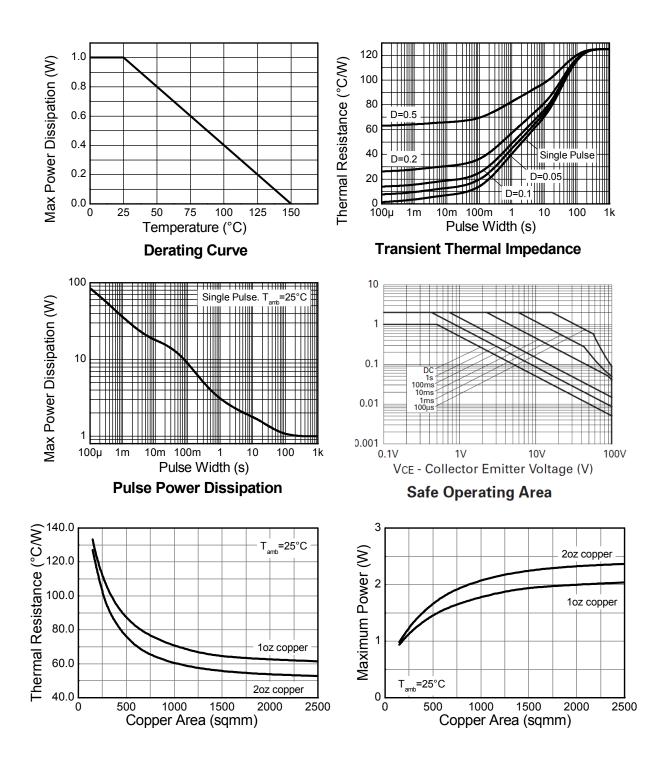
9. Thermal resistance from junction to the top of the case.

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





# Thermal Characteristics and Derating Information







# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

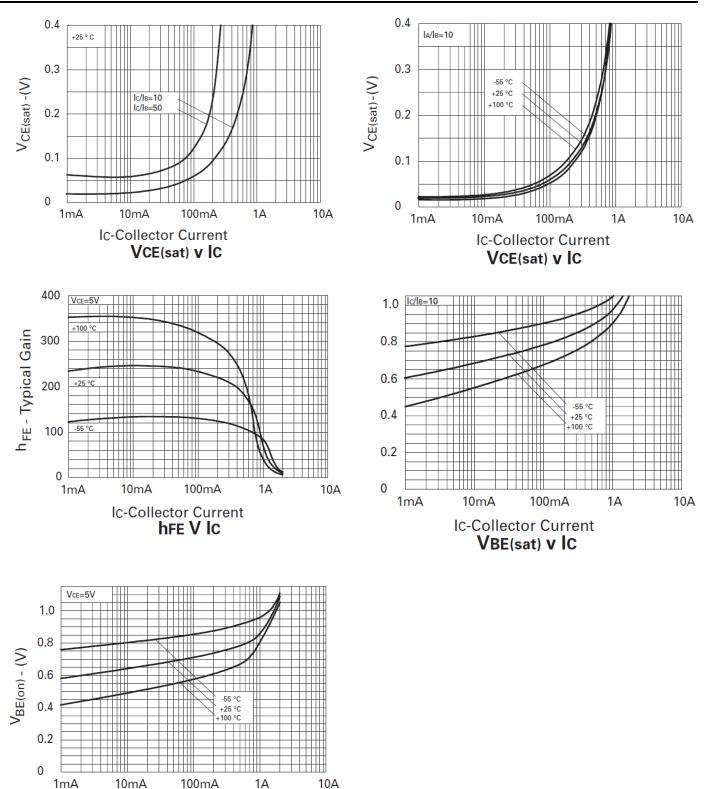
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-120			V	$I_{\rm C} = -100 \mu \text{A}$
Collector-Emitter Breakdown Voltage (Note 11)	BVCBO	-100	_	_	V	$I_{\rm C} = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_		V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>		_	-100	nA	V <sub>CB</sub> = -100V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5V
Emitter Cutoff Current	ICES	_	_	-100	nA	V <sub>CES</sub> = -100V
DC current transfer Static ratio (Note 11)	hfe	100 100 100 50	_	 300 	_	$I_{C} = -1mA, V_{CE} = -5V$ $I_{C} = -250mA, V_{CE} = -5V$ $I_{C} = -500mA, V_{CE} = -5V$ $I_{C} = -1A, V_{CE} = -5V$
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	_	_	-0.2 -0.3	V	I <sub>C</sub> = -250mA, I <sub>B</sub> = -25mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>		_	-1.1	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Turn-on Voltage (Note 11)	V <sub>BE(on)</sub>	_	—	-1.0	V	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V
Transitional Frequency	fT	50	_	_	MHz	I <sub>E</sub> = -50mA, V <sub>CE</sub> = -10V f = 100MHz
Output capacitance	C <sub>obo</sub>	_	—	5	pF	V <sub>CB</sub> = -10V, f = 1MHz,

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.





# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



VBE(on) v lc

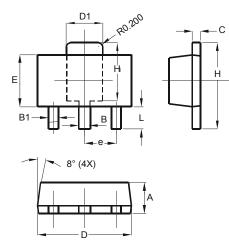
**IC-Collector Current** 





# **Package Outline Dimensions**

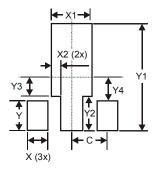
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
E	2.29	2.60		
е	е 1.50 Тур			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





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